



RELIABILITY REPORT FOR

# DS1922L, iButton w-Battery and SMT Crystal, RoHS

## **Dallas Semiconductor**

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Prepared by:

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#### **Conclusion:**

The following qualification successfully meets the quality and reliability standards required of all Dallas Semiconductor products and processes:

DS1922L, iButton w-Battery and SMT Crystal, RoHS

In addition, Dallas Semiconductor's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport /dsreliability.html.\*

#### **Module Description**

A description of this Module can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l\_datasheet3.cfm.\*

### **Reliability Derating:**

A module device consists of one or more IC's in a single, upward integrated, package. This package is assembled to include batteries, crystals, and other piece parts that make up the configuration of the Module. Because of either the complexity of the package or the included piece parts, standard high temperature reliability testing is not possible. Therefore, in order to determine the reliability of module products, the reliability of each of the piece parts is individually determined, then summed to determine the reliability of the integrated module product. If there are "n" significant components in the module then:

Fr (module) = Fr (1) + Fr (2) + Fr (3) + .... + Fr (n) Fr (module) = Failure rate of module Fr(n) = Failure rate of the nth component

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

			-				
Module Device:	Module Units:	Quantity:	<u>Fails:</u>	<u>Ea:</u>	Beta:	MTTF (Yrs):	<u>FITs:</u>
BR1225	1	100	1	1.0	0.0	175984	0.6
CRYSTAL	1	100	0	0.7	0.0	12463	9.2
DS2422	1	231	0	0.7	0.0	19833	5.8
DS9503	1	152	0	0.7	0.0	17861	6.4
Totals:						5199	22.0

The calculated failure rate for this module/assembly is:

The parameters used to calculate the module failure rate are as follows

Cf: 60% Tu: 25 °C Vu: 5.5 Volts

The reliability data follows. At the start of this data is the module assembly information. This is a description of the module. The next section is the detailed reliability data for each stress found in the qualification / monitor. If there are additional processes or assemblies used as part of this report, a description of each will follow which includes the respective reliability data for that process/ assembly. The reliability data section includes the latest data available. Some of this data may be generic with other packages or products.

\* Some proprietary products may be excepted from this requirement

Assembly Inform	nation:																				
Assembly Site:		Fastech																			
Pin Count:		2																			
Package Type: Body Size: Mold Compound: Lead Frame: Lead Finsh: Die Attach: Bond Wire / Size: Flammability:		Puk Can F50 Insert Mold Bump, Battery w-SMT Crystal (RoHS)																			
		68																			
		BCB PCB; FR4 High Pb Ball (95/5) Underfill FP4527, Dexter Hysol NA / NA UL 94-V0																			
											Moisture Sensi		NA								
											(JEDEC J-ST	,									
											Date Code Rar	nge:	0653	to	0703						
											STORAGE LIFE										
											DESCRIPTION	DATE CD	CONDITION				REA	READPOINT		FAILS	FA#
STORAGE LIFE	0653	85 C				500	HRS	77	0												
STORAGE LIFE	0653	85 C				500	HRS	77	0												
STORAGE LIFE	0703	85 C				500	HRS	77	0												
							Total:		0												
TEMPERATURE C	YCLE																				
DESCRIPTION	DATE CD	CONDITION				REA	READPOINT		FAILS	FA#											
TEMP CYCLE	0703	-40 TO 85	5C			500	CYS	77	0												
TEMP CYCLE	0653	-40 TO 85	5C			1000	CYS	77	0												
TEMP CYCLE	0653	-40 TO 85	5C			1000	CYS	77	0												
							Total:		0												
UNBIASED MOIST	URE RESIST	ANCE																			
DESCRIPTION	DATE CD	CONDITION			REA	DPOINT	QTY	FAILS	FA#												
MOISTURE SOAK	0653	85 C/85%	5 R.H.			500	HRS	77	0												
MOISTURE SOAK	0653	85 C/85%	5 R.H.			500	HRS	77	0												
MOISTURE SOAK	0703	85 C/85%	5 R.H.			500	HRS	77	0												
							Total:		0												

Although this was a RoHS construction part/qualification, this qualification covers both RoHS and non-RoHS products. The process flow for this construction is reflow (Eutectic or Pb-free) crystal side first, followed by reflow (Eutectic) flip chip side second.